Non-Linear Hall Effect in Flatlands and Chiral Crystals

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Acknowledgments

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Discussions:

S. Mandal, H. R. Krishnamurthy, M. Jain (IISc)

N. Spaldin, S. Bhowal (ETH Zurich)

M. Deshmukh (TIFR)

Pancharatnam-Berry Phase

• Adiabatic evolution of a quantum state

 $|\Psi_n(t)\rangle = e^{i\gamma_n(t)}e^{-\frac{i}{\hbar}\int_0^t dt'\varepsilon_n(R(t'))}|n(R(t))\rangle$

• Geometric phase can arise

$$
\gamma_n(t) = i \int_0^t \langle n(R(t')) \vert \frac{d}{dt'} \vert n(R(t')) \rangle
$$

$$
= i \int_{R(0)}^{R(t)} dR \langle n(R) \vert \nabla_R \vert n(R) \rangle
$$

S. Pancharatnam (1934-1969)

M. V. Berry (1941-)

 \cdot Can define a connection and a curvature

 $\mathcal{A}_n(R) = i \langle n(R) | \nabla_R | n(R) \rangle \qquad \Omega_n(R) = \nabla_R \times \mathcal{A}_n(R)$

Berry curvature and quantum Hall effect

- Pancharatnam-Berry phases underpin many diverse quantum phenomena
- Celebrated quantum Hall effect

$$
\sigma_{ab} = -\frac{e^2}{\hbar} \varepsilon_{abc} \int \frac{d^n k}{(2\pi)^n} \Omega_c f_0
$$

• Need to break time reversal symmetry

Berry Curvature Dipole and Non-Linear Hall Effect

- Usual (linear) Hall effect vanishes in time reversal invariant systems
- Time-reversal invariant systems with low-enough symmetry can show non-linear Hall effect

Sodemann and Fu, Phys. Rev. Lett. 115, 216806 (2015)

• Second-order response

$$
\chi_{abc} = -\frac{e^3 \tau}{2(1 + i\omega\tau)} \varepsilon_{adc} \int \frac{d^n k}{(2\pi)^n} (\partial_b \Omega_d) f_0
$$

$$
\partial_a = \partial/\partial k_a
$$

Berry Curvature Dipole and Non-Linear Hall Effect

• Underlying origin is the first-order moment of Berry curvature: Berry curvature dipole

$$
D_{ab} = \int \frac{d^n k}{(2\pi)^n} (\partial_a \Omega_b) f_0
$$

$$
\partial_a = \partial / \partial k_a
$$

Can be generalized to higher order moments

Roy and Narayan, J. Phys.: Condens. Matter 35, 385301 (2022)

Non-Linear Hall Effect: Experimental Realization I

• First experimental realization in bilayer and few-layer $WTe₂$

Ma *et al.*, Nature 565, 337 (2019)

Kang *et al.*, Nature Materials 18, 324 (2019)

• Dual gated geometry measures voltage response at 2*ω*, when current applied at *ω*

Non-Linear Hall Effect: Experimental Realization II

Twisted double bilayer graphene **Artificially corrugated graphene**

Sinha *et al.*, Nature Physics 18, 765 (2022)

Oxide interfaces

Ho *et al.*, Nature Electronics 4, 116 (2021)

Recent review: Bandyopadhyay, Joseph, and Narayan, Materials Today Electronics 8, 100101 (2024)

Plan for this talk

Graphene analogs: Silicene, Germanene and Stanene

$$
\vec{E} \uparrow \circ \bullet \bullet \bullet \bullet \bullet \bullet \bullet \bullet \bullet \vec{1}
$$

Bandyopadhyay, Joseph, and Narayan, 2D Materials 9, 035013 (2022)

Chiral Materials: Metals, semimetals and semiconductors

Joseph, Bandyopadhyay, and Narayan, Chemistry of Materials, in press (2024)

Focus on the intrinsic contribution only!

Plan for this talk

Graphene analogs: Silicene, Germanene and Stanene

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Graphene Analogs: Silicene, Germanene, Stanene

Binding energy (eV) -0.5 0.0 0.5 5.5 nm \times 5.5 nm Momentum k (A^{-1})

Vogt *et al.*, Phys. Rev. Lett. 108, 155501 (2012) Zhu *et al.*, Nature Materials 14, 1020 (2015)

- Possible signatures of two-dimensional variants of Si, Ge and Sn
- Honeycomb structure, but not planar
- Potential to exploit larger spin orbit coupling than graphene

Topology of silicene, germanene, stanene

Xu *et al.*, Phys. Rev. Lett. 111, 136804 (2013) Ezawa, JPSJ 84, 121003 (2015)

- Topologically non-trivial nature theoretically identified early on
- Unambiguous measurement of edge states still awaited

Buckled Honeycomb Layers: Symmetries

- Maximum permitted symmetry for finite BCD in 2D: single mirror line
- Apply uniaxial strain to remove C_{3} and two σ_{d} reflection symmetry planes
- Electric field breaks inversion symmetry

Buckled Honeycomb Layers: Tight-binding model

$$
\hat{H} = - t \sum_{\langle ij \rangle, \sigma} c_{i,\sigma}^{\dagger} c_{j,\sigma} + i \frac{\lambda_{SO}}{3\sqrt{3}} \sum_{\langle\langle ij \rangle\rangle, \sigma} \sigma \zeta_{ij} c_{i,\sigma}^{\dagger} c_{j,\sigma} - i \sum_{i,\sigma} \nu_i E_z c_{i,\sigma}^{\dagger} c_{i,\sigma}.
$$

- Silicene, germanene, stanene can be described by same model with different values of the parameters
- Kane-Mele type of spin orbit coupling
- Electric field resulting in staggered sublattice potential
- Tight-binding results cross-checked with density functional computations

Buckled Honeycomb Layers: Electric Field Tunable Topology

- Electric field strongly controls the band structure
- Quantum spin Hall insulator to zero gap semimetal to trivial insulator

Buckled Honeycomb Layers: Electric Field Tunable Topology

- Phase diagram of strained system similar to pristine case
- Focus near electric field critical value E_c^{\parallel}

Buckled Honeycomb Layers: Electric Field Tunable Berry **Curvature**

- Berry curvature flips sign across the topological phase transition
- Indicates interesting Berry curvature dipole physics

Buckled Honeycomb Layers: Electric Field Tunable Berry Curvature Dipole

- Giant peak in BCD around Fermi level near critical electric fields
- Enhanced BCD a signature of topological to trivial insulator transition

Buckled Honeycomb Layers: Electric Field Tunable Berry Curvature Dipole

- Giant peak in BCD around Fermi level near critical electric fields
- Enhanced BCD a signature of topological to trivial insulator transition
- Sign of BCD flipped on either side of topological phase transition
- Values highest among untwisted two-dimensional materials

Plan for this talk

Graphene analogs: Silicene, Germanene and **Stanene**

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Bandyopadhyay, Joseph, and Narayan, 2D Materials 9, 035013 (2022)

Chiral Materials: Metals, semimetals and semiconductors

Joseph, Bandyopadhyay, and Narayan, Chemistry of Materials, in press (2024)

Chirality: A brief Introduction

Term first used by Kelvin (1893): "*I call any geometrical figure, or group of points, 'chiral', and say that it has chirality if its image in a plane mirror, ideally realized, cannot be brought to coincide with itself."*

Fecher *et al.*, Materials 15, 5812 (2022)

Quanta Magazine: *Magnetism May Have Given Life Its Molecular Asymmetry* (2023)

• Concept of chirality widespread across physics, chemistry, biology...

Chiral Crystals

A crystal structure is chiral if its space group consists of only proper operations - rotations and translations

> Elemental Tellurium $P3,21$ $P3₂21$

- Inversion, mirror plane, roto-inversion and glide are improper operations
- A number of intriguing aspects of chiral materials have been discovered: interplay with topology, phonons, ferroelectricity
- Non-linear Hall effects?

Chiral Crystals: A simple model

- Honeycomb model inspired by graphene and DNA
- Adjacent hopping parameters are unequal
- Next-nearest neighbour hopping has a handedness results in chirality

Chiral Crystals: A simple model

$$
H = \sum_{\langle i,j \rangle} [t_{ij} a_i^{\dagger} b_j + h.c.] + \sum_{\langle \langle i,j \rangle \rangle} [g_{ij}^l a_i^{\dagger} a_j + g_{ij}^r b_i^{\dagger} b_j + h.c].
$$

- g' zero for right-handed structure, g' zero for left-handed one
- Broken inversion symmetry

Simple model: Berry curvature

- Broken inversion gives a non-zero Berry curvature
- Concentrated near the band edges as expected

Simple model: Berry curvature

- Broken inversion gives a non-zero Berry curvature
- Concentrated near the band edges as expected
- Right-handed structure has an exactly opposite Berry curvature

Simple model: Berry curvature dipole

- Two non-zero components of BCD $D_{_{XZ}}$ and $D_{_{YZ}}$
- Right- and left-handed structures give an exactly opposite value of BCD component
- What about real materials?

NbSi2: A chiral metal

- Crystallizes in enantiomeric pairs opposite orientations of Nb-Si-Nb chains
- Metallic with predominantly Nb *d* orbital contribution near Fermi level
- Identical band structure of two enantiomers

NbSi2: Berry curvature

- Berry curvature components have opposite signs for two enantiomers
- A number of Berry curvature hotspots slightly away from Fermi level

NbSi2: Berry curvature dipole tensor symmetries

• Crystal point symmetries impose constraints on the BCD tensor

 $D = det(S)SDS^{T}$

• For $NbSi₂$, one finds the form

$$
D = \pm D_{xx} \begin{bmatrix} 1 & 0 & 0 \\ 0 & 1 & 0 \\ 0 & 0 & -2 \end{bmatrix}
$$

• Off-diagonal elements vanish

NbSi2: Berry curvature dipole

- All components of BCD have opposite signs for two enantiomers
- Peaks occur due to rapidly varying Berry curvature
- Values at Fermi level slightly smaller than TMDCs
- Non-Linear Hall effect a way to distinguish enantiomeric pairs?

Trigonal Te: An elemental chiral material

- "Hydrogen atom" of chiral materials
- Narrow band gap with topological band crossings in valence and conduction manifolds
- Need hybrid DFT for accurate band structure

Trigonal Te: Berry curvature and dipole

- Opposite Berry curvature for two enantiomers
- Weyl points with topological charge also opposite in two enantiomers
- BCD components change sign for the enantiomers

Summary

Graphene analogs: Silicene, Germanene and Stanene

$$
\vec{E} \uparrow \circ \bullet \text{!}
$$

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Chiral Materials: Metals, semimetals and semiconductors

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